# Medium power transistor (60V, 2A)

# 2SC5866

### Features

1) High speed switching. (Tf: Typ.: 35ns at Ic = 2A)

2) Low saturation voltage, typically

(Typ.: 200mV at Ic = 1.0m, IB = 0.1A)

- 3) Strong discharge power for inductive load and capacitance load.
- 4) Complements the 2SA2094

# Applications

Low frequency amplifier High speed switching

#### Structure

NPN Silicon epitaxial planar transistor

# Packaging specifications

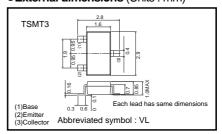
	Package	Taping
Туре	Code	TL
	Basic ordering unit (pieces)	3000
2SC5866		0

# ● Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
Collector-base voltage	Vсво	60	V
Collector-emitter voltage	Vceo	60	V
Emitter-base voltage	Vево	6	V
Callantan sumant	Ic	2	А
Collector current	ICP	4	A *1
Power dissipation	Pc	500	mW *2
Junction temperature	Tj	150	°C
Range of storage temperature	Tstg	-55 to +150	°C

<sup>1</sup> Pw=10ms

# ●External dimensions (Units : mm)



<sup>\*2</sup> Each terminal mounted on a recommended land.

# ●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-base breakdown voltage	ВУсво	60	_	_	V	Ic=100μA
Collector-emitter breakdown voltage	BVceo	60	_	_	V	Ic=1mA
Emitter-base breakdown voltage	ВУево	6	-	_	V	IE=100μA
Collector cut-off current	Ісво	_	_	1.0	μΑ	Vcb=40V
Emitter cut-off current	ІЕВО	-	-	1.0	μΑ	V <sub>EB</sub> =4V
Collector-emitter staturation voltage	VCE(sat)	-	200	500	mV	Ic=1A, Iв=0.1A *1
DC current gain	hfe	120	-	390	_	VcE=2V, Ic=100mA
Transition frequency	fT	_	200	_	MHz	Vc==10V, I==-100mA, f=10MHz*1
Collector output capacitance	Cob	_	10	_	pF	Vcb=10V, Ie=0mA, f=1MHz
Turn-on time	Ton	_	50	_	ns	Ic=2A, I <sub>B1</sub> =200mA
Storage time	Tstg	_	120	_	ns	
Fall time	Tf	_	35	_	ns	Vcc≒25V *2

<sup>\*1</sup> Non repetitive pulse

# ●hfe RANK

Q	R		
120-270	180-390		

# Electrical characteristic curves

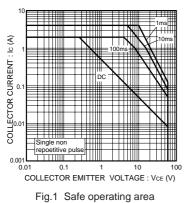


Fig.1 Safe operating area

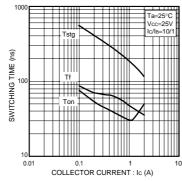


Fig.2 Switching Time

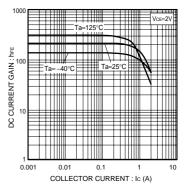
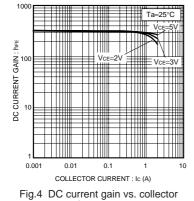


Fig.3 DC current gain vs. collector current



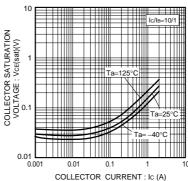


Fig.5 Collector-emitter saturation voltage vs. Collector Current

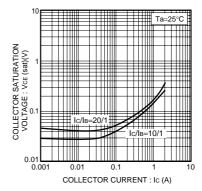


Fig.6 Collector-emitter saturation voltage vs. collector current

<sup>\*2</sup> See switching charactaristics measurement circuits

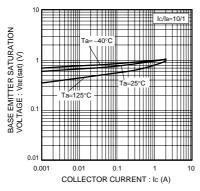


Fig.7 Base-emitter saturation voltage vs. collector current

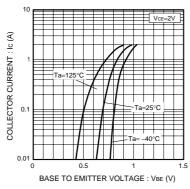


Fig.8 Ground emitter propagation characteristics

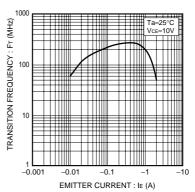


Fig.9 Transition frequency

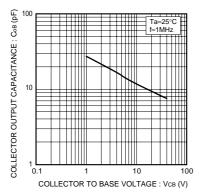
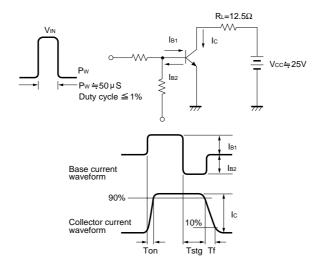


Fig.10 Collector output capacitance

# Switching characteristics measurement circuits



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